

2020

Novel Skew Compensation Techniques for Reducing EMI from Differential Traces

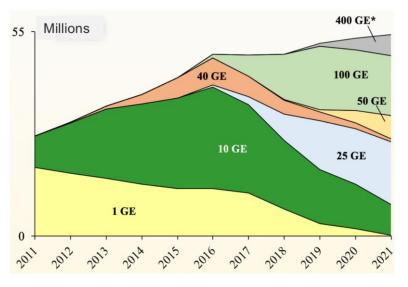
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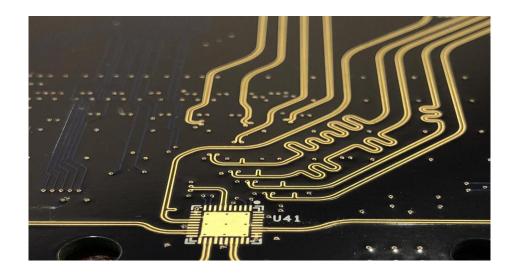
Background

- The switch port speed goes higher to 100G, 400G, etc.
- Differential pairs are commonly used in high speed switch design
- EMI benefits diminish if there is any imbalance in differential routing
- The skew due to bend is the main imbalance
- Current skew compensation techniques are not optimized





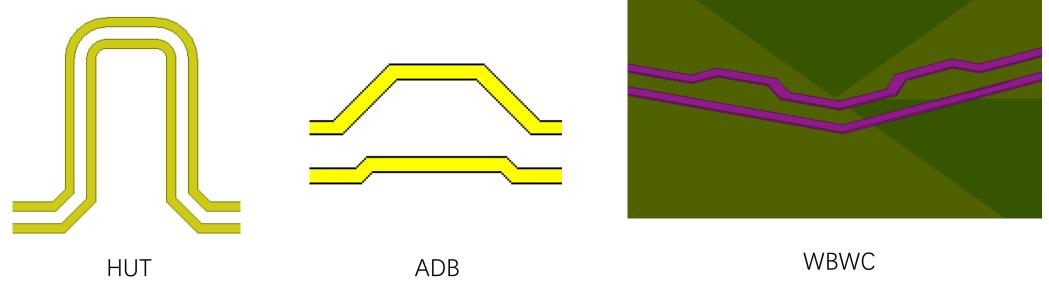




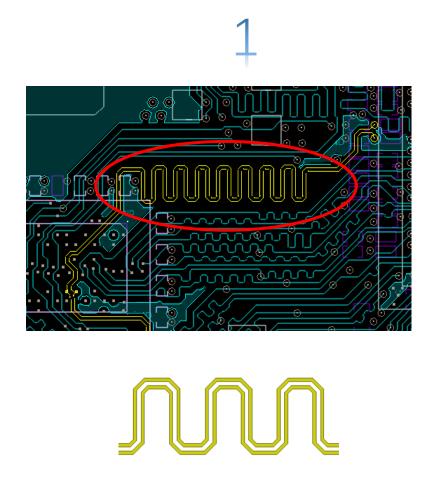


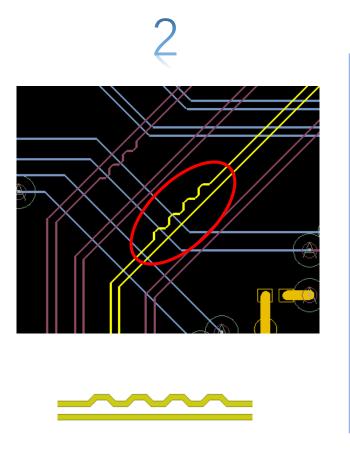
Three Skew Compensation Techniques for Reducing EMI from Differential Traces

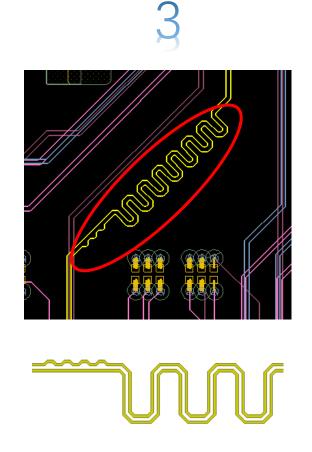
- Hybrid U Turn(HUT), Published in APEMC2017
- Asymmetric Dual Bend(ADB) structure for skew compensation,
 Patent pending in USPTO, Paper accepted by 2020 IEEE International Symposium on EMC/SI/PI
- Localized skew compensation technique for reducing EMI(WBWC), US Patent US 8835775 B2



Hybrid U Turn ---- Background





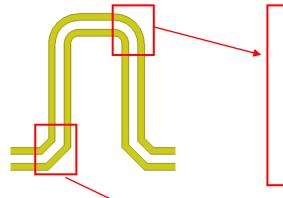


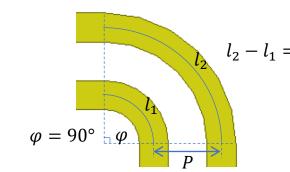


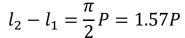
Hybrid U Turn ---- illustration

Published in APEMC2017

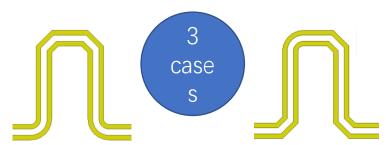


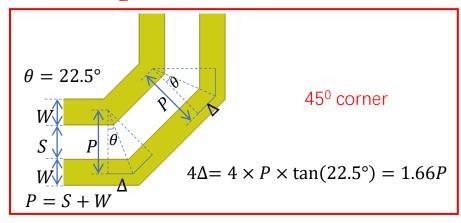






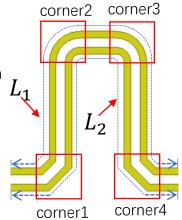
Round corner

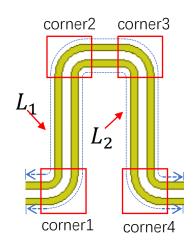




Two functions in one symbol:

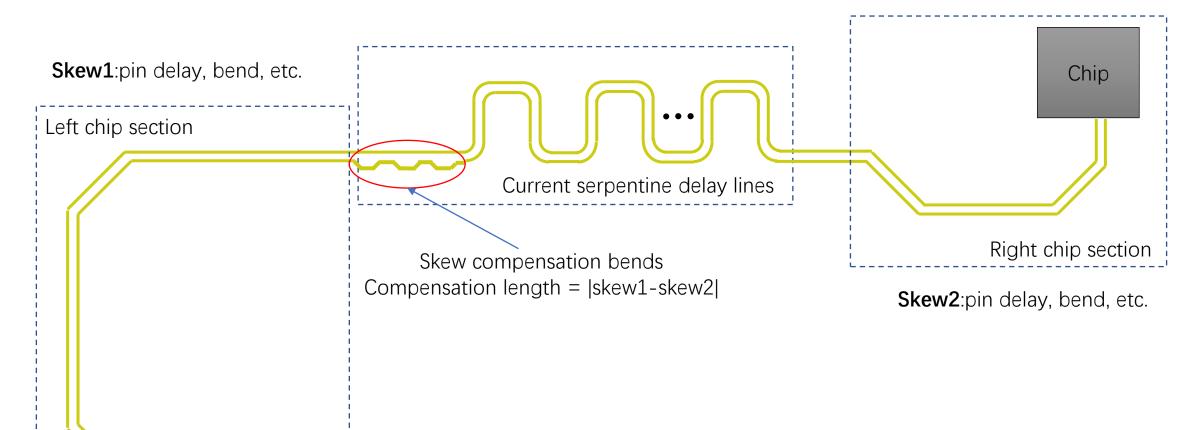
- 1. Tune time budget or keep the same length with other channels
- 2. Mitigate skew in its channel, one symbol get **0.18***P* skew compensation



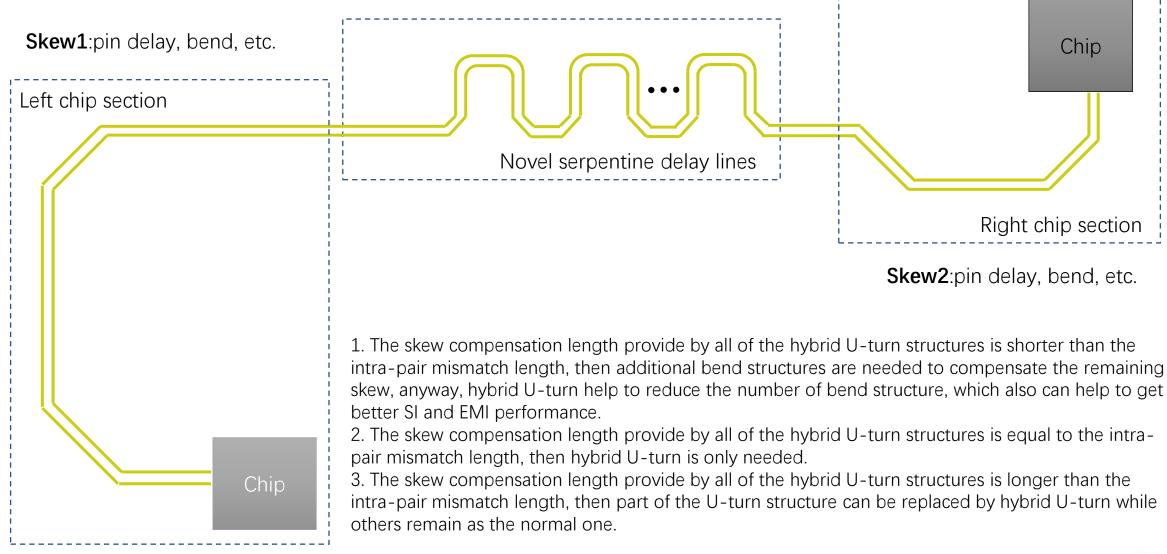


Hybrid U Turn ---- Current routing scheme

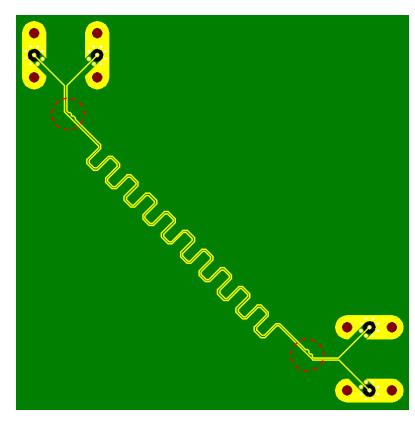
Chip



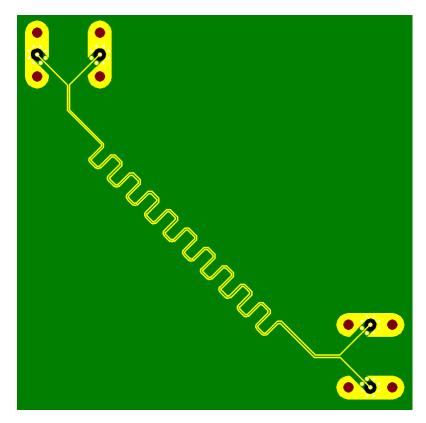
Hybrid U Turn ---- Routing with Hybrid U-Turn



Hybrid U Turn ---- Simulation model



Current layout

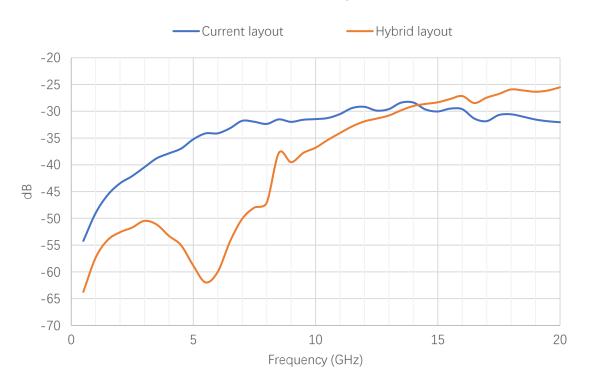


Hybrid layout

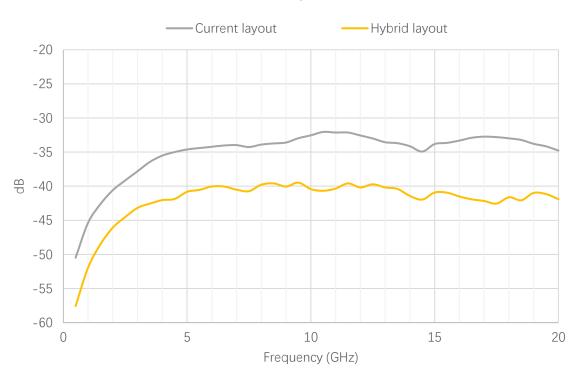


Hybrid U Turn ---- Scd21





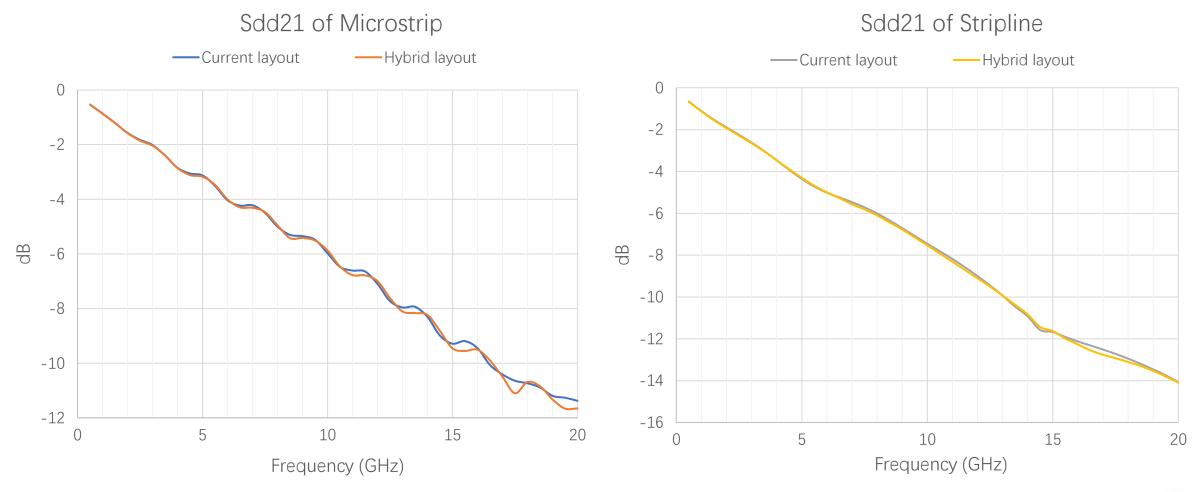
Scd21 of Stripline



$$V_{common.MAX} = \frac{V_{in}}{4t_r} \cdot min\{2\tau, \Delta t\}, \Delta t = T_{even} - T_{odd}$$

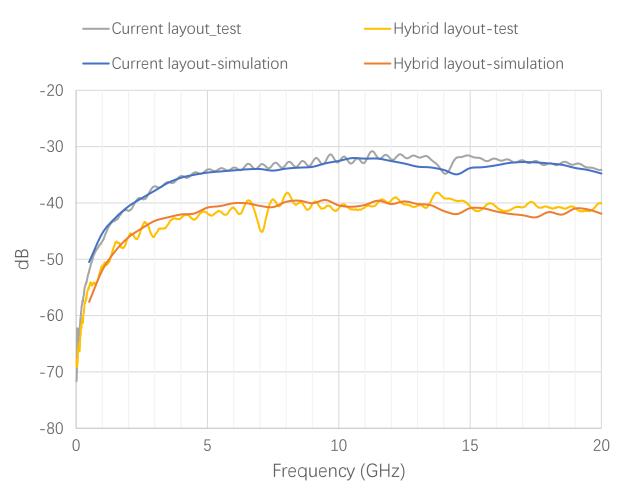
- L. Hybrid U-turn structures are farther from skew bend than current compensation scheme
- 2. The propagation constant of even mode and odd mode in microstrip are different

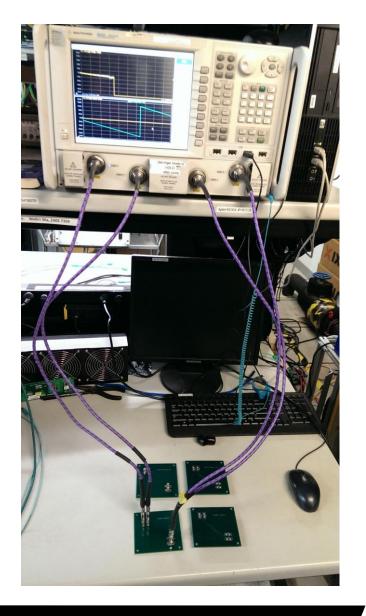
Hybrid U Turn ---- Sdd21



Hybrid U Turn ---- Scd21 verification

Scd21 by test



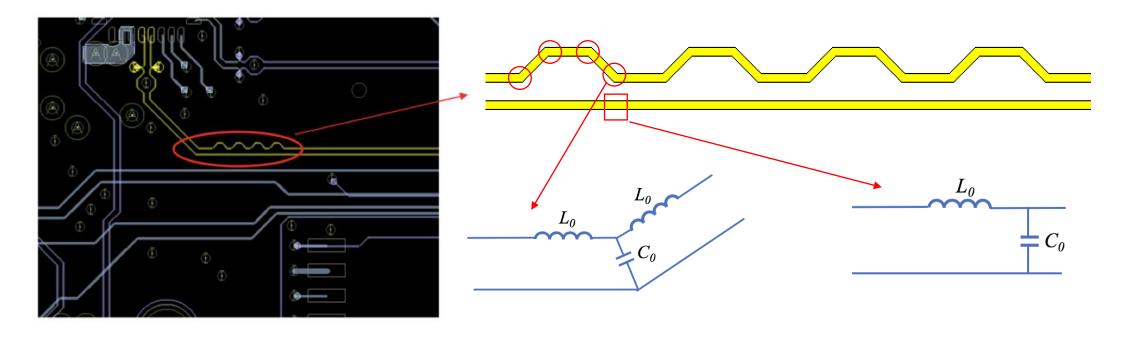




Hybrid U Turn ---- Conclusion

- A novel differential serpentine delay line is proposed which have both inter and intra-pair length matching function
- 5-15dB reduction in differential to common mode conversion

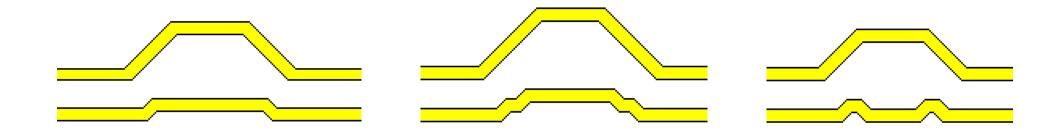
Asymmetric Dual Bend ---- Background



The bends can help to compensate the skew between two traces of differential pair, additionally, each bend also introduces four corners in one trace while the other trace is still straight, which may bring imbalance between two trace and lead to differential to common mode conversion



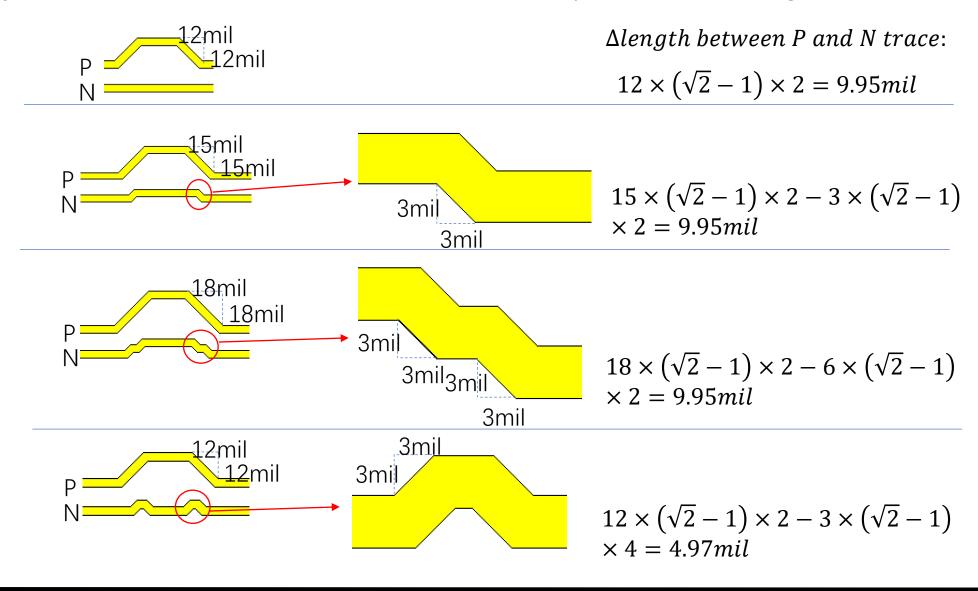
Asymmetric Dual Bend ---- 3 new bends



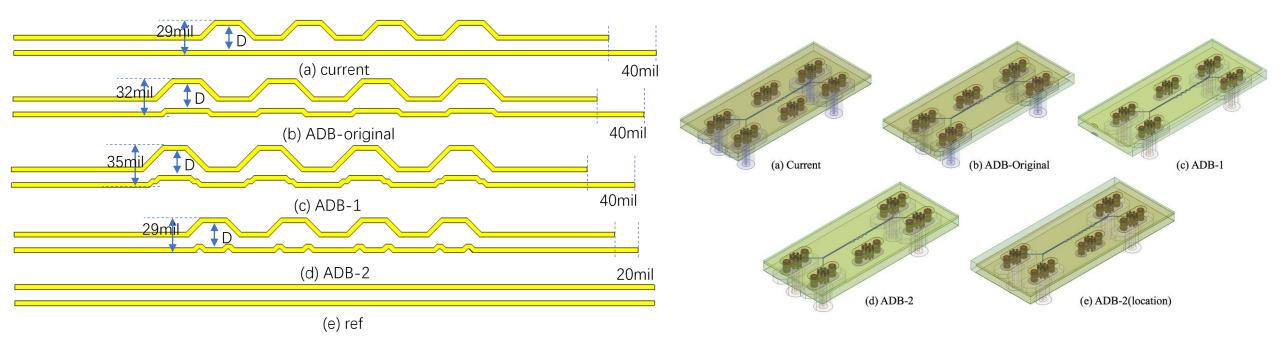
Patent pending in USPTO
Paper accepted by 2020 IEEE International Symposium on EMC/SI/PI



Asymmetric Dual Bend ---- Skew compensation length of each bend

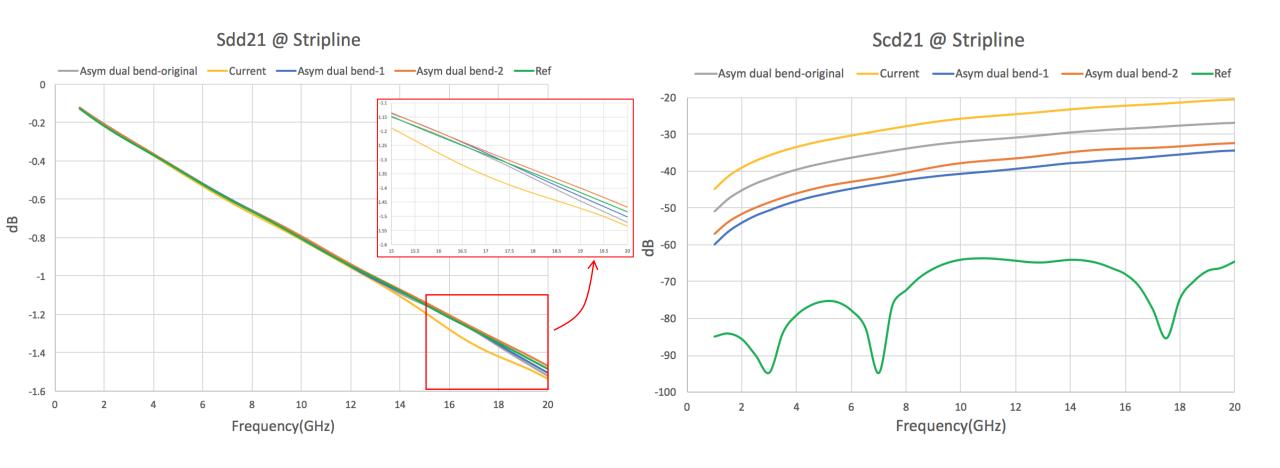


Asymmetric Dual Bend ---- Simulation cases

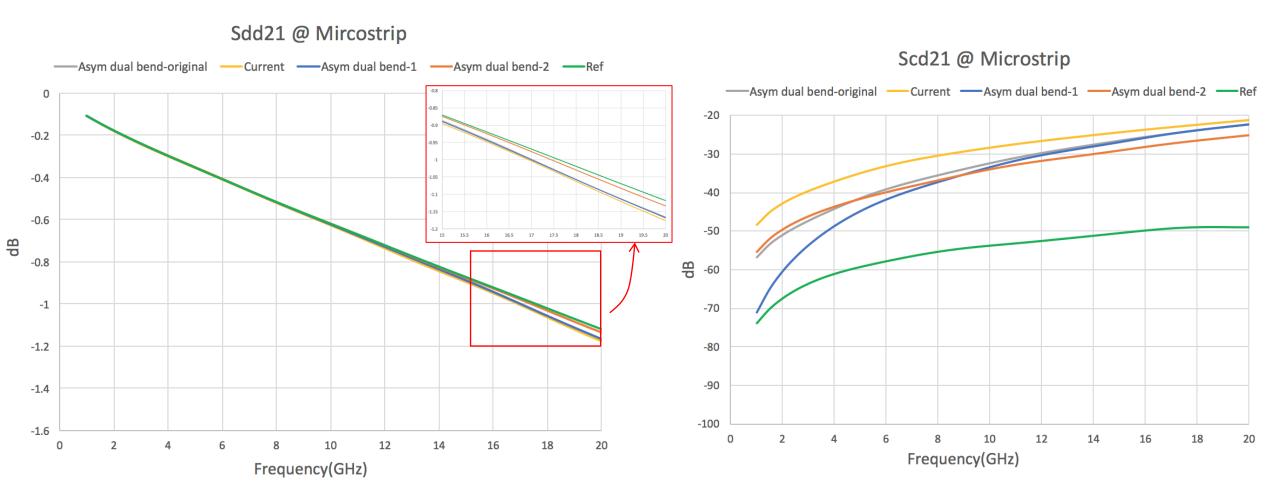




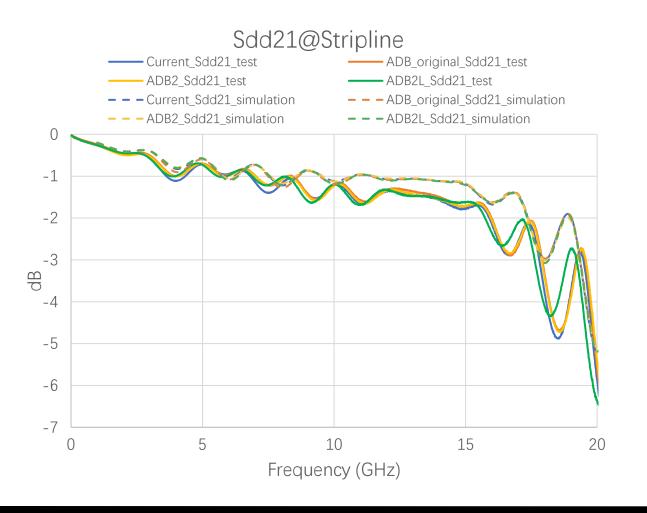
Asymmetric Dual Bend ---- Stripline simulation

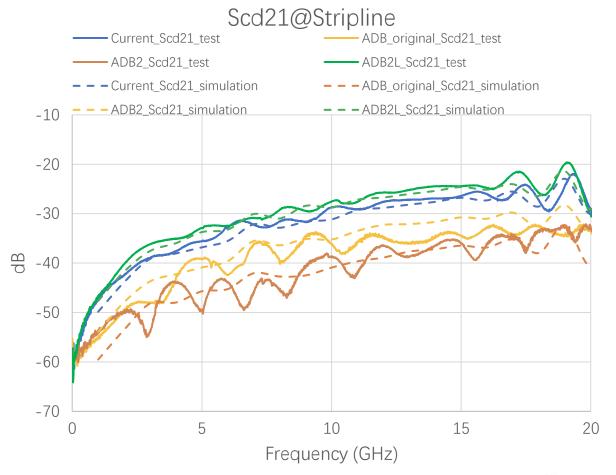


Asymmetric Dual Bend ---- Microstrip simulation



Asymmetric Dual Bend ---- Simulation Vs Measurement

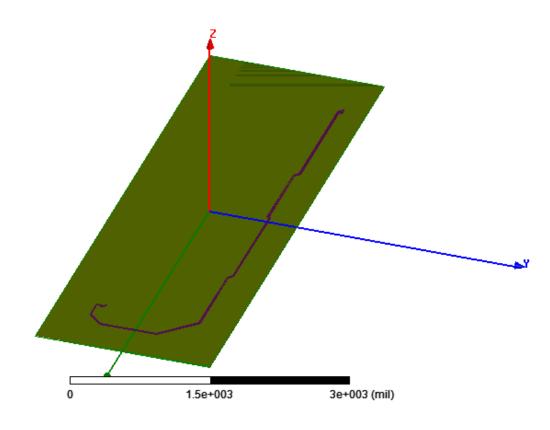




Asymmetric Dual Bend ---- Conclusion

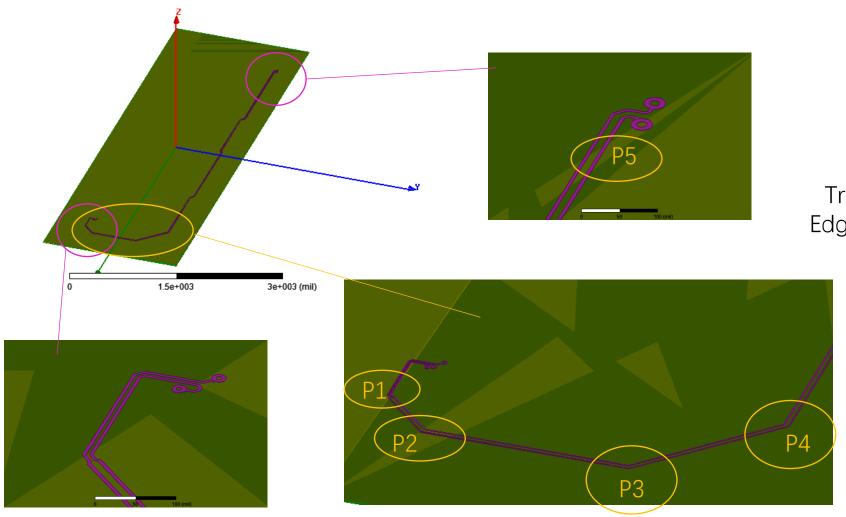
- Asymmetric dual bend (ADB) introduces bends in both P and N traces of differential pair to compensate the skew
- ADB provides 10+ dB improvement for Scd21 in stripline layout and nearly 5dB improvement for microstrip layout

Localized skew compensation technique ---- Background



- Bend layout introduce skew of differential pair
- Differential pair is required to have an equal length for signal integrity concerns. Therefore bends are added on the shorter trace.
- In practical PCB routing, CAD engineers usually count the length of trace pairs at the final stage, and then put a few bends to deskew the pair length wherever there is a space. Does randomly placing the bends impact the EMI performance?

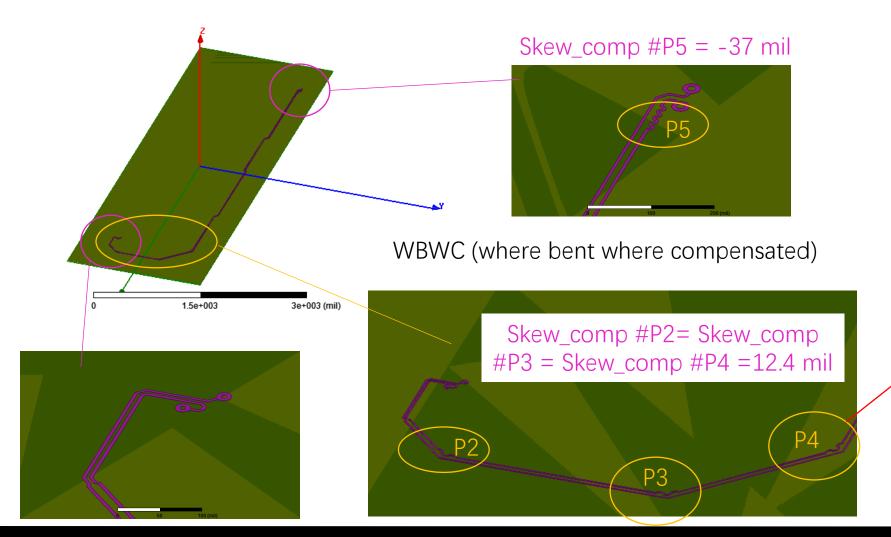
Localized skew compensation technique ---- Old design

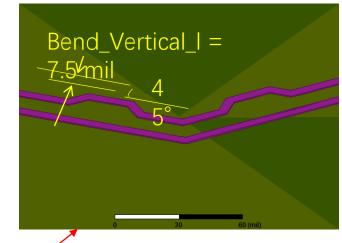


Length = 6376 mil
Trace width = 4.7 mil
Trace thickness = 0.65 mil
Edge to edge spacing = 10.3
mil

FR4 height = 3.6 mil ϵ_r = 4, tan δ = 0.02 Z_0 = 59.3 Ohm

Localized skew compensation technique ---- Improved design

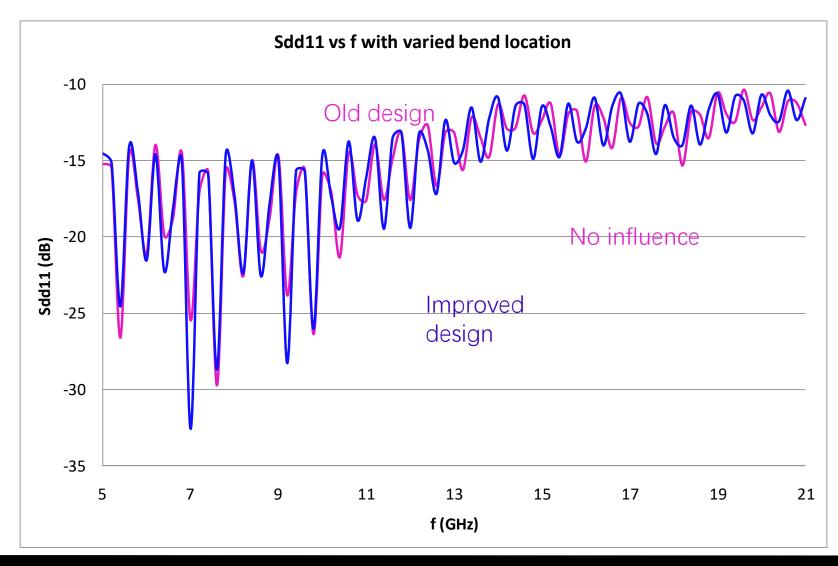




US Patent US 8835775 B2



Localized skew compensation technique ---- Sdd11

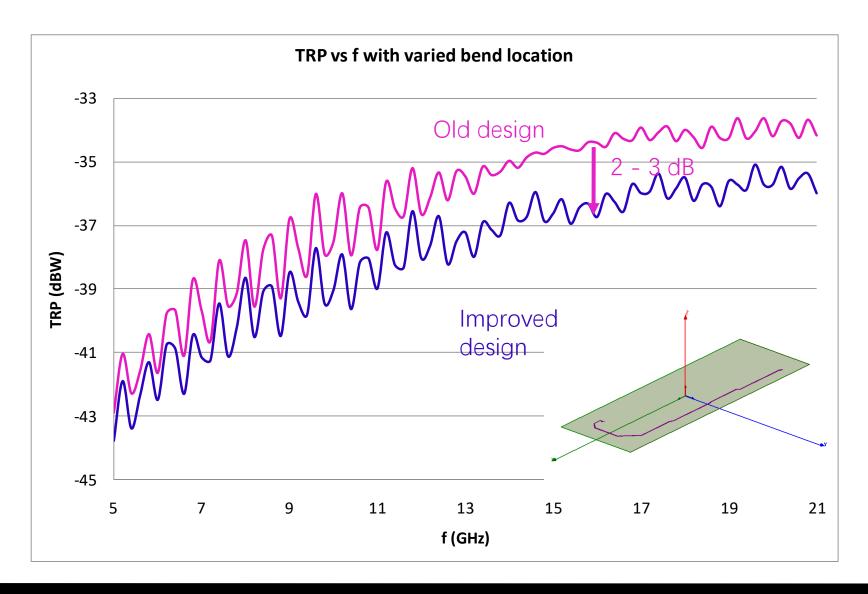


Localized skew compensation technique ---- Sdd21





Localized skew compensation technique ---- TRP





Localized skew compensation technique ---- Conclusion

- A new compensation approach named by 'WBWC (where bent where compensated)' is proposed here.
- No influence on reflection loss.
- 1 dB improvement on differential mode insertion loss.
- 2-3 dB reduction on Total radiated power(TRP)



- Three skew compensation techniques for reducing EMI from differential traces are proposed
- The performance is simulated by Ansys HFSS, and shows good improvement
- The simulation results are verified by PCB coupon measurement





